

SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

# DS25BR440 3.125 Gbps Quad LVDS Buffer with Transmit Pre-Emphasis and Receive Equalization

Check for Samples: DS25BR440

# FEATURES

www.ti.com

- DC 3.125 Gbps Low Jitter, Low Skew, Low Power Operation
- Pin Selectable Transmit Pre-Emphasis and Receive Equalization Eliminate Data Dependant Jitter
- Wide Input Common Mode Voltage Range Allows DC-Coupled Interface to LVDS, CML and LVPECL Drivers
- LOS Circuitry Detects Open Inputs Fault
- Integrated 100Ω Input and Output Terminations
- 8 kV ESD on LVDS I/O Pins Protects Adjoining Components
- Small 6 mm x 6 mm WQFN-40 Space Saving Package

# **APPLICATIONS**

- Clock and Data Buffering and Repeating
- Copper Cable Driving and Equalization
- FR-4 Equalization
- OC-48 / STM-16

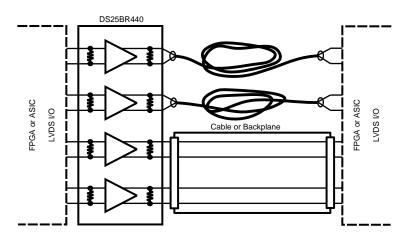
### **Typical Application**

# DESCRIPTION

The DS25BR440 is a 3.125 Gbps Quad LVDS buffer optimized for high-speed signal routing and repeating over lossy FR-4 printed circuit board backplanes and balanced cables. Fully differential signal paths ensure exceptional signal integrity and noise immunity.

The DS25BR440 features two levels of transmit preemphasis (PE) and two levels of receive equalization (EQ). Both of these features compensate for interconnect losses and <u>ultimately</u> maximize noise margin. A loss-of-signal (LOS) circuit monitors each input channel and a unique LOS pin is asserted when no signal is detected at that input.

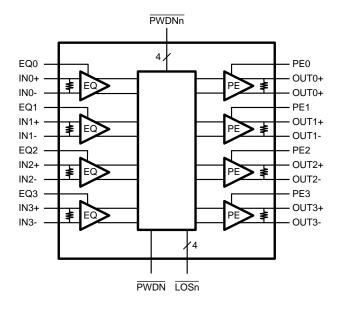
Wide input common mode range allows the switch to accept signals with LVDS, CML and LVPECL levels; the output levels are LVDS. A very small package footprint requires a minimal space on the board while the flow-through pinout allows easy board layout. Each differential input and output is internally terminated with a  $100\Omega$  resistor to lower device return losses, reduce component count and further minimize board space.



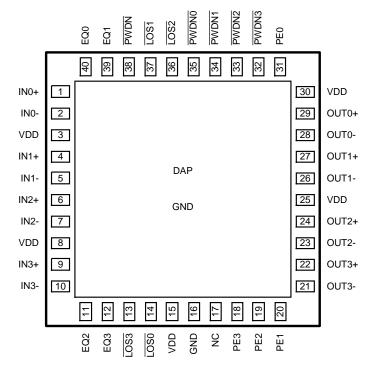
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.



#### **Block Diagram**



# **Connection Diagram**



DS25BR440 Pin Diagram



#### SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

PIN DESCRIPTIONS							
Pin Name	Pin Number	I/O, Type	Pin Description				
IN0+, IN0- , IN1+, IN1-, IN2+, IN2-, IN3+, IN3-	1, 2, 4, 5, 6, 7, 9, 10	I, LVDS	Inverting and non-inverting high speed LVDS input pins.				
OUT0+, OUT0-, OUT1+, OUT1-, OUT2+, OUT2-, OUT3+, OUT3-	29, 28, 27, 26, 24, 23, 22, 21	O, LVDS	Inverting and non-inverting high speed LVDS output pins.				
EQ0, EQ1, EQ2, EQ3	40, 39, 11, 12	I, LVCMOS	Receive equalization level select pins.				
PE0, PE1, PE2, PE3	31, 20, 19, 18	I, LVCMOS	Transmit pre-emphasis level select pins.				
PWDN0, PWDN1, PWDN2, PWDN3	35, 34, 33, 32	I, LVCMOS	Channel output power down pins. When the $\overline{PWDNn}$ is set to L, the channel output OUTn is in the power down mode. The LOS circuitry on the corresponding input remains enabled.				
<u>LOS0</u> , <u>LOS1</u> , LOS2, LOS3	14, 37, 36, 13	O, LVCMOS	Loss Of Signal output pins, LOSn report when an open input fault condition is detected at the input, INn. These are open drain outputs. External pull up resistors are required.				
NC	17	NC	NO CONNECT pins. May be left floating.				
PWDN	38	I, LVCMOS	Device power down pin. When the $\overline{\text{PWDN}}$ is set to L, the device is in the power down mode. The $\overline{\text{LOS}}$ circuitry is disabled as well.				
VDD	3, 8, 15,25, 30	Power	Power supply pins.				
GND	16, DAP	Power	Ground pin and a pad (DAP - die attach pad).				



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



### Absolute Maximum Ratings<sup>(1)(2)</sup>

Supply Voltage	-0.3V to +4V
LVCMOS Input Voltage	-0.3V to (V <sub>CC</sub> + 0.3V)
LVCMOS Output Voltage	-0.3V to (V <sub>CC</sub> + 0.3V)
LVDS Input Voltage	-0.3V to +4V
Differential Input Voltage  VID	1V
LVDS Output Voltage	-0.3V to (V <sub>CC</sub> + 0.3V)
LVDS Differential Output Voltage	0.0V to +1V
LVDS Output Short Circuit Current Duration	5 ms
Junction Temperature	+150°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature Range Soldering (4 sec.)	+260°C
Maximum Package Power Dissipation at 25°C	
RTA0040A Package	2.44W
Derate RTA0040A Package	19.49 mW/°C above +25°C
Package Thermal Resistance	
θ <sub>JA</sub>	+26.9°C/W
θ <sub>JC</sub>	+3.8°C/W
ESD Susceptibility	
HBM <sup>(3)</sup>	≥8 kV
MM <sup>(4)</sup>	≥250V
CDM <sup>(5)</sup>	≥1250V

(1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions.

(2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.

(3) Human Body Model, applicable std. JESD22-A114C

(4) Machine Model, applicable std. JESD22-A115-A

(5) Field Induced Charge Device Model, applicable std. JESD22-C101-C

### **Recommended Operating Conditions**

	Min	Тур	Max	Units
Supply Voltage (V <sub>CC</sub> )	3.0	3.3	3.6	V
Receiver Differential Input Voltage (VID)	0		1	V
Operating Free Air Temperature (T <sub>A</sub> )	-40	+25	+85	°C

#### **Electrical Characteristics**

Over recommended operating supply and temperature ranges unless otherwise specified. <sup>(1)</sup> <sup>(2)</sup> <sup>(3)</sup>

Symbol	Parameter	Conditions	Min	Тур	Max	Units
LVCMO	S DC SPECIFICATIONS					
V <sub>IH</sub>	High Level Input Voltage		2.0		V <sub>DD</sub>	V
V <sub>IL</sub>	Low Level Input Voltage		GND		0.8	V
I <sub>IH</sub>	High Level Input Current	V <sub>IN</sub> = 3.6V V <sub>CC</sub> = 3.6V		0	±10	μA

(1) The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

(2) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V<sub>OD</sub> and ΔV<sub>OD</sub>.

(3) Typical values represent most likely parametric norms for  $V_{CC} = +3.3V$  and  $T_A = +25^{\circ}C$ , and at the Recommended Operation Conditions at the time of product characterization and are not guaranteed.



SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

www.ti.com

#### **Electrical Characteristics (continued)**

Over recommended operating supply and temperature ranges unless otherwise specified. (1) (2) (3)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
IIL	Low Level Input Current	$V_{IN} = GND$ $V_{CC} = 3.6V$		0	±10	μA
V <sub>CL</sub>	Input Clamp Voltage	$I_{CL} = -18 \text{ mA}, V_{CC} = 0 \text{V}$		-0.9	-1.5	V
V <sub>OL</sub>	Low Level Output Voltage	I <sub>OL</sub> = 4 mA		0.26	0.4	V
LVDS IN	IPUT DC SPECIFICATIONS					-
V <sub>ID</sub>	Input Differential Voltage		0		1	V
V <sub>TH</sub>	Differential Input High Threshold	$V_{CM}$ = +0.05V or $V_{CC}$ -0.05V		0	+100	mV
V <sub>TL</sub>	Differential Input Low Threshold		-100	0		mV
V <sub>CMR</sub>	Common Mode Voltage Range	V <sub>ID</sub> = 100 mV	0.05		V <sub>CC</sub> - 0.05	V
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = +3.6V or 0V V <sub>CC</sub> = 3.6V or 0V		±1	±10	μA
C <sub>IN</sub>	Input Capacitance	Any LVDS Input Pin to GND		1.7		pF
R <sub>IN</sub>	Input Termination Resistor	Between IN+ and IN-		100		Ω
LVDS O	UTPUT DC SPECIFICATIONS			- <u>1</u>	<u>.</u>	•
V <sub>OD</sub>	Differential Output Voltage		250	350	450	mV
ΔV <sub>OD</sub>	Change in Magnitude of V <sub>OD</sub> for Complimentary Output States	$R_L = 100\Omega$	-35		35	mV
V <sub>OS</sub>	Offset Voltage		1.05	1.2	1.375	V
ΔV <sub>OS</sub>	Change in Magnitude of V <sub>OS</sub> for Complimentary Output States	$R_L = 100\Omega$	-35		35	mV
l <sub>os</sub>	Output Short Circuit Current <sup>(4)</sup>	OUT to GND		-35	-55	mA
		OUT to V <sub>CC</sub>		7	55	mA
C <sub>OUT</sub>	Output Capacitance	Any LVDS Output Pin to GND		1.2		pF
R <sub>OUT</sub>	Output Termination Resistor	Between OUT+ and OUT-		100		Ω
SUPPLY	CURRENT					-
I <sub>CC</sub>	Supply Current	PE = OFF, EQ = OFF PWDN = H		162	190	mA
I <sub>CCZ</sub>	Power Down Supply Current	PWDN = L		55	63	mA

(4) Output short circuit current (I<sub>OS</sub>) is specified as magnitude only, minus sign indicates direction only.

### AC Electrical Characteristics (1) (2)

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Units			
LVDS OUTPUT A	VDS OUTPUT AC SPECIFICATIONS								
t <sub>PLHD</sub>	Differential Propagation Delay Low to High $^{\rm (3)}$	P 1000		390	600	ps			
t <sub>PHLD</sub>	Differential Propagation Delay High to Low $^{\rm (3)}$	$R_{L} = 100\Omega$		400	600	ps			
t <sub>SKD1</sub>	Pulse Skew  t <sub>PLHD</sub> - t <sub>PHLD</sub>			10	50	ps			

(1) The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

(2) Typical values represent most likely parametric norms for  $V_{CC} = +3.3V$  and  $T_A = +25^{\circ}C$ , and at the Recommended Operation Conditions at the time of product characterization and are not guaranteed.

(3) Specification is guaranteed by characterization and is not tested in production.

(4) t<sub>SKD1</sub>, |t<sub>PLHD</sub> - t<sub>PHLD</sub>], Pulse Skew, is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.

TEXAS INSTRUMENTS

www.ti.com

# AC Electrical Characteristics <sup>(1) (2)</sup> (continued)

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter Conditions		litions	Min	Тур	Max	Units
t <sub>SKD2</sub>	Channel to Channel Skew				18	65	ps
t <sub>SKD3</sub>	Part to Part Skew (3) (6)				50	170	ps
t <sub>LHT</sub>	Rise Time <sup>(3)</sup>				80	160	ps
t <sub>HLT</sub>	Fall Time <sup>(3)</sup>	$R_L = 100\Omega$			80	160	ps
t <sub>ON</sub>	Any PWDN to Output Active Time				8	20	μs
t <sub>OFF</sub>	Any PWDN to Output Inactive Time				5	12	ns
JITTER PERFO	RMANCE WITH EQ = Off, PE = Off $^{(3)}$ (F	igure 5)		-			
t <sub>RJ1</sub>	Random Jitter (RMS Value)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.5	1	ps
t <sub>RJ2</sub>	No Test Channels	V <sub>CM</sub> = 1.2V Clock (RZ)	3.125 Gbps		0.5	1	ps
t <sub>DJ1</sub>	Deterministic Jitter (Peak to Peak)	$V_{ID} = 350 \text{ mV}$	2.5 Gbps		6	22	ps
t <sub>DJ2</sub>	No Test Channels	V <sub>CM</sub> = 1.2V K28.5 (NRZ)	3.125 Gbps		10	29	ps
t <sub>TJ1</sub>	Total Jitter (Peak to Peak)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.04	0.09	$UI_{P-P}$
t <sub>TJ2</sub>	No Test Channels	V <sub>CM</sub> = 1.2V PRBS-23 (NRZ)	3.125 Gbps		0.06	0.14	UI <sub>P-P</sub>
JITTER PERFO	RMANCE WITH EQ = Off, PE = On <sup>(3)</sup> (Fi	igure 6, Figure 9)					
t <sub>RJ1B</sub>	Random Jitter (RMS Value)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.5	1	ps
t <sub>RJ2B</sub>	Test Channel B	V <sub>CM</sub> = 1.2V Clock (RZ)	3.125 Gbps		0.5	1	ps
t <sub>DJ1B</sub>	Deterministic Jitter (Peak to Peak)	V <sub>ID</sub> = 350 mV	2.5 Gbps		7	15	ps
t <sub>DJ2B</sub>	Test Channel B (7) Deterministic Jitter (Peak to Peak) Test Channel B (8)	V <sub>CM</sub> = 1.2V K28.5 (NRZ)	3.125 Gbps		4	23	ps
t <sub>TJ1B</sub>	Total Jitter (Peak to Peak)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.05	0.10	UI <sub>P-P</sub>
t <sub>TJ2B</sub>	Test Channel B	V <sub>CM</sub> = 1.2V PRBS-23 (NRZ)	3.125 Gbps		0.06	0.14	UI <sub>P-P</sub>
JITTER PERFO	RMANCE WITH EQ = On, PE = Off <sup>(11)</sup> (F	Figure 7, Figure 9)					-
t <sub>RJ1D</sub>	Random Jitter (RMS Value)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.5	1	ps
t <sub>RJ2D</sub>	Test Channel D (12)	V <sub>CM</sub> = 1.2V Clock (RZ)	3.125 Gbps		0.5	1	ps
t <sub>DJ1D</sub>	Deterministic Jitter (Peak to Peak)	V <sub>ID</sub> = 350 mV	2.5 Gbps		14	30	ps
t <sub>DJ2D</sub>	Test Channel D	V <sub>CM</sub> = 1.2V K28.5 (NRZ)	3.125 Gbps		15	30	ps
t <sub>TJ1D</sub>	Total Jitter (Peak to Peak)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.08	0.15	UI <sub>P-P</sub>
t <sub>TJ2D</sub>	Test Channel D	V <sub>CM</sub> = 1.2V PRBS-23 (NRZ)	3.125 Gbps		0.10	0.17	UI <sub>P-P</sub>
JITTER PERFO	RMANCE WITH EQ = On, PE = On <sup>(11)</sup> (F	igure 8, Figure 9)		1			
t <sub>RJ1BD</sub>	Random Jitter (RMS Value)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.5	1	ps
t <sub>RJ2BD</sub>	Input Test Channel D Output Test Channel B	V <sub>CM</sub> = 1.2V Clock (RZ)	3.125 Gbps		0.5	1	ps

(5) t<sub>SKD2</sub>, Channel to Channel Skew, is the difference in propagation delay (t<sub>PLHD</sub> or t<sub>PHLD</sub>) among all output channels in Broadcast mode (any one input to all outputs).

(6)  $t_{SKD3}$ , Part to Part Skew, is defined as the difference between the minimum and maximum differential propagation delays. This specification applies to devices at the same  $V_{CC}$  and within 5°C of each other within the operating temperature range.

(7) Measured on a clock edge with a histogram and an accumulation of 1500 histogram hits. Input stimulus jitter is subtracted geometrically.
(8) Tested with a combination of the 1100000101 (K28.5+ character) and 0011111010 (K28.5- character) patterns. Input stimulus jitter is subtracted algebraically.

(9) Measured on an eye diagram with a histogram and an accumulation of 3500 histogram hits. Input stimulus jitter is subtracted.

(10) Measured on an eye diagram with a histogram and an accumulation of 3500 histogram hits. Input stimulus jitter is subtracted.

(11) Specification is guaranteed by characterization and is not tested in production.

(12) Measured on a clock edge with a histogram and an accumulation of 1500 histogram hits. Input stimulus jitter is subtracted geometrically.
 (13) Tested with a combination of the 1100000101 (K28.5+ character) and 0011111010 (K28.5- character) patterns. Input stimulus jitter is subtracted algebraically.



#### SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

# AC Electrical Characteristics <sup>(1)</sup> <sup>(2)</sup> (continued)

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Conditi	ons	Min	Тур	Max	Units
t <sub>DJ1BD</sub>	Deterministic Jitter (Peak to Peak)	V <sub>ID</sub> = 350 mV	2.5 Gbps		11	23	ps
t <sub>DJ2BD</sub>		V <sub>CM</sub> = 1.2V K28.5 (NRZ)	3.125 Gbps		5	24	ps
t <sub>TJ1BD</sub>	Total Jitter (Peak to Peak)	V <sub>ID</sub> = 350 mV	2.5 Gbps		0.08	0.14	$UI_{P}$
t <sub>TJ2BD</sub>	Input Test Channel D Output Test Channel B (10)	V <sub>CM</sub> = 1.2V PRBS-23 (NRZ)	3.125 Gbps		0.10	0.20	UI <sub>P-P</sub>



SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

DC TEST CIRCUITS

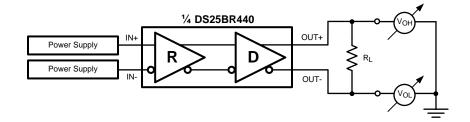


Figure 1. Differential Driver DC Test Circuit

# **AC Test Circuits and Timing Diagrams**

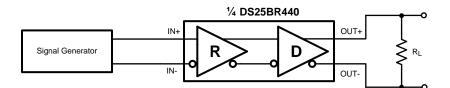


Figure 2. Differential Driver AC Test Circuit

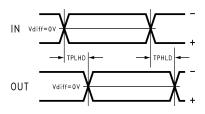


Figure 3. Propagation Delay Timing Diagram

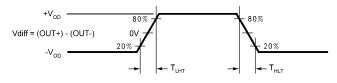
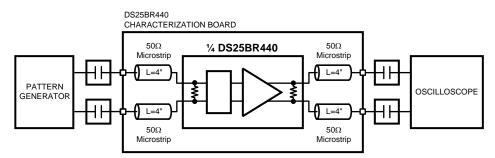


Figure 4. LVDS Output Transition Times

# **Pre-Emphasis and Equalization Test Circuits**







SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

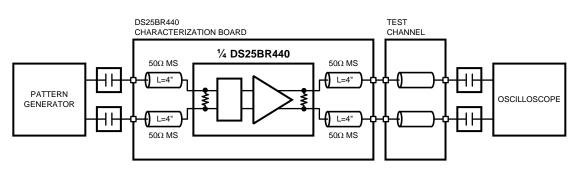


Figure 6. Pre-emphasis Performance Test Circuit

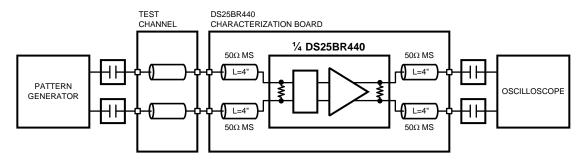


Figure 7. Equalization Performance Test Circuit

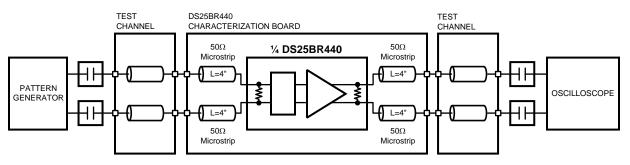


Figure 8. Pre-emphasis and Equalization Performance Test Circuit

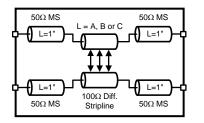


Figure 9. Test Channel Block Diagram

### **Test Channel Loss Characteristics**

The test channel was fabricated with Polyclad PCL-FR-370-Laminate/PCL-FRP-370 Prepreg materials (Dielectric constant of 3.7 and Loss Tangent of 0.02). The edge coupled differential striplines have the following geometries: Trace Width (W) = 5 mils, Gap (S) = 5 mils, Height (B) = 16 mils.



SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

www.ti.com

Test Channel	Length	Insertion Loss (dB)					
	(inches)	500 MHz	750 MHz	1000 MHz	1250 MHz	1500 MHz	1560 MHz
А	10	-1.2	-1.7	-2.0	-2.4	-2.7	-2.8
В	20	-2.6	-3.5	-4.1	-4.8	-5.5	-5.6
С	30	-4.3	-5.7	-7.0	-8.2	-9.4	-9.7
D	15	-1.6	-2.2	-2.7	-3.2	-3.7	-3.8
E	30	-3.4	-4.5	-5.6	-6.6	-7.7	-7.9
F	60	-7.8	-10.3	-12.4	-14.5	-16.6	-17.0

### **Functional Description**

The DS25BR440 is a 3.125 Gbps Quad LVDS buffer optimized for high-speed signal routing and repeating over lossy FR-4 printed circuit board backplanes and balanced cables.

The DS25BR440 has a pre-emphasis control pin for each output for switching the transmit pre-emphasis to ON and OFF setting and an equalization control pin for each input for switching the receive equalization to ON and OFF setting. The following are the transmit pre-emphasis and receive equalization truth tables.

#### Table 1. Transmit Pre-Emphasis Truth Table<sup>(1)</sup>

OUTPUT OUTn, n = {0, 1, 2, 3}				
CONTROL Pin (PEn) State	Pre-emphasis Level			
0	OFF			
1	ON			

(1) Transmit Pre-emphasis Level Selection for an Output OUTn

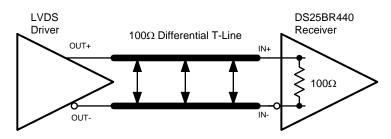
#### Table 2. Receive Equalization Truth Table<sup>(1)</sup>

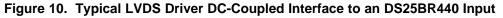
INPUT INn, n = {0, 1, 2, 3}				
CONTROL Pin (EQn) State	Equalization Level			
0	OFF			
1	ON			

(1) Receive Equalization Level Selection for an Input INn

#### Input Interfacing

The DS25BR440 accepts differential signals and allows simple AC or DC coupling. With a wide common mode range, the DS25BR440 can be DC-coupled with all common differential drivers (i.e. LVPECL, LVDS, CML). The following three figures illustrate typical DC-coupled interface to common differential drivers. Note that the DS25BR440 inputs are internally terminated with a  $100\Omega$  resistor.

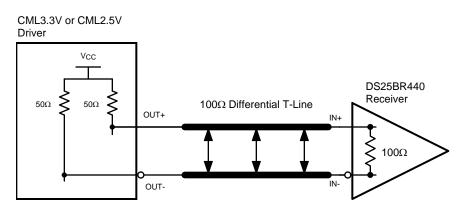




TEXAS INSTRUMENTS

www.ti.com

SNLS258B-FEBRUARY 2008-REVISED MARCH 2013





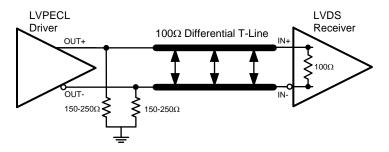
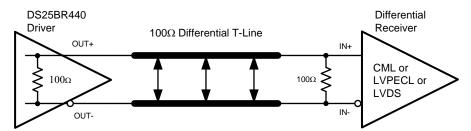


Figure 12. Typical LVPECL Driver DC-Coupled Interface to an DS25BR440 Input

### Output Interfacing

The DS25BR440 outputs signals compliant to the LVDS standard. Its outputs can be DC-coupled to most common differential receivers. The following figure illustrates typical DC-coupled interface to common differential receivers and assumes that the receivers have high impedance inputs. While most differential receivers have a common mode input range that can accommodate LVDS compliant signals, it is recommended to check the respective receiver's data sheet prior to implementing the suggested interface implementation.





SNLS258B-FEBRUARY 2008-REVISED MARCH 2013



www.ti.com



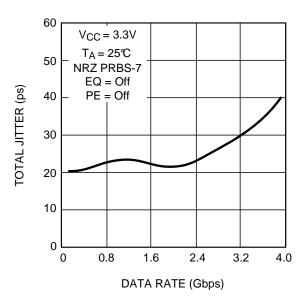


Figure 14. Total Jitter as a Function of Data Rate

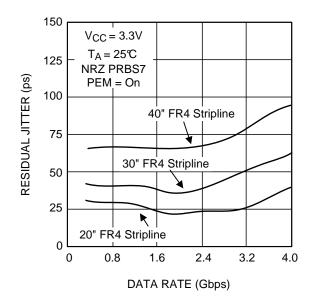


Figure 16. Residual Jitter as a Function of Data Rate, FR4 Stripline Length and PE Level

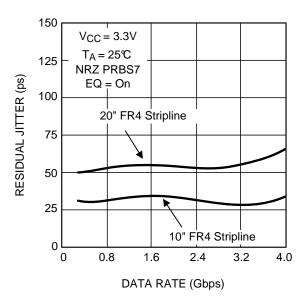


Figure 15. Residual Jitter as a Function of Data Rate, FR4 Stripline Length and EQ Level

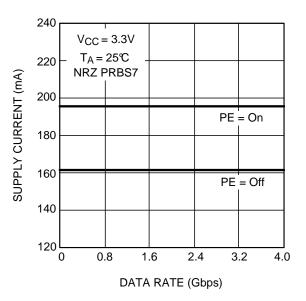


Figure 17. Supply Current as a Function of Data Rate and PE Level



SNLS258B-FEBRUARY 2008-REVISED MARCH 2013

# **REVISION HISTORY**

Changes from Revision A (March 2013) to Revision B			
•	Changed layout of National Data Sheet to TI format	12	



10-Dec-2020

# PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DS25BR440TSQ/NOPB	ACTIVE	WQFN	RTA	40	250	RoHS & Green	SN	Level-3-260C-168 HR		2BR440SQ	Samples
DS25BR440TSQX/NOPB	ACTIVE	WQFN	RTA	40	2500	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 85	2BR440SQ	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

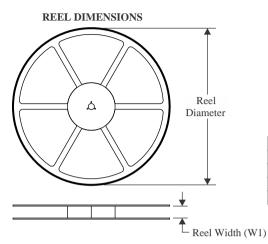


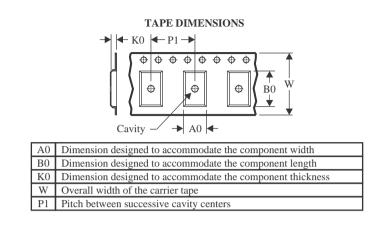
# PACKAGE OPTION ADDENDUM

10-Dec-2020



# TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	•	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS25BR440TSQ/NOPB	WQFN	RTA	40	250	178.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1
DS25BR440TSQX/NOPB	WQFN	RTA	40	2500	330.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1



# PACKAGE MATERIALS INFORMATION

27-Sep-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS25BR440TSQ/NOPB	WQFN	RTA	40	250	208.0	191.0	35.0
DS25BR440TSQX/NOPB	WQFN	RTA	40	2500	356.0	356.0	36.0

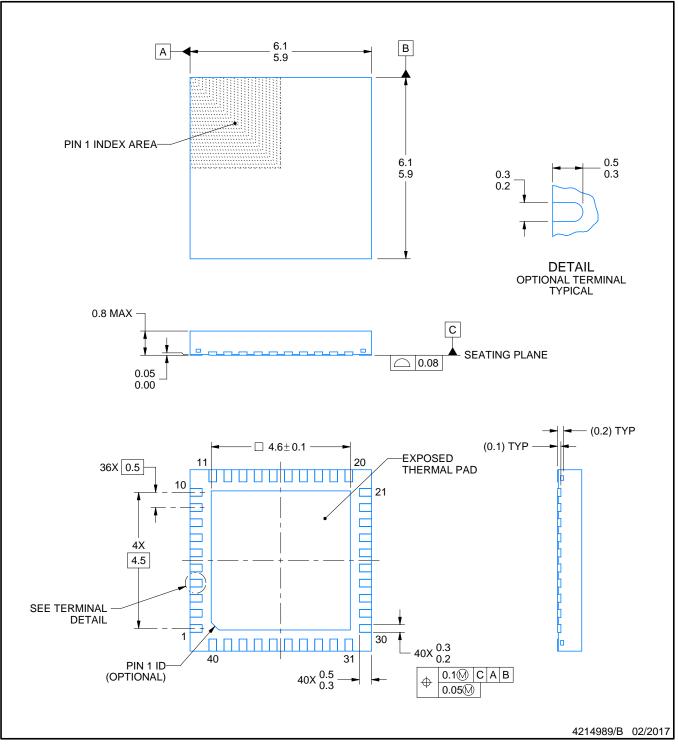
# **RTA0040A**



# **PACKAGE OUTLINE**

# WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

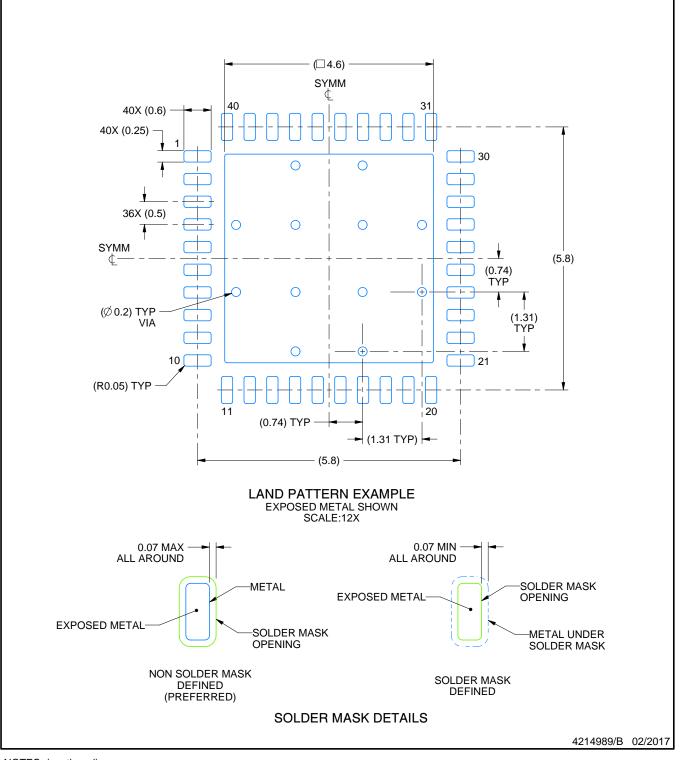


# **RTA0040A**

# **EXAMPLE BOARD LAYOUT**

# WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

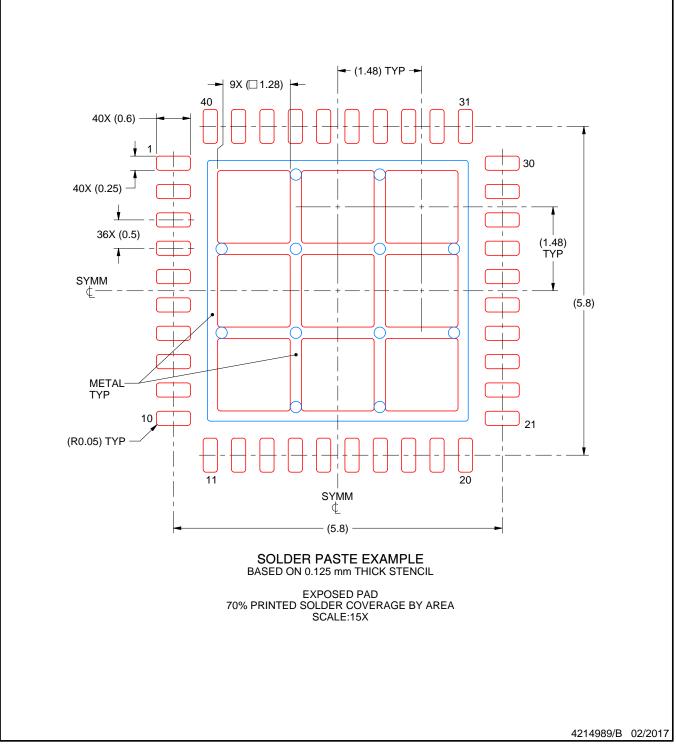


# **RTA0040A**

# **EXAMPLE STENCIL DESIGN**

# WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



# IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated